

Features

- Temperature ranges
 - Commercial: 0 °C to 70 °C
- High speed
 - $t_{AA} = 8 \text{ ns}$
- Low active power
 - 360 mW (max)
- 2.0 V data retention
- Automatic power down when deselected
- TTL-compatible inputs and outputs
- Easy memory expansion with \overline{CE} and \overline{OE} features

Functional Description

The CY7C1049CV33 is a high performance CMOS Static RAM organized as 524,288 words by eight bits. Easy memory expansion is provided by an active LOW Chip Enable (\overline{CE}), an active LOW Output Enable (\overline{OE}), and three-state drivers. Writing to the device is accomplished by taking Chip Enable (\overline{CE}) and Write Enable (\overline{WE}) inputs LOW. Data on the eight I/O pins (I/O_0 through I/O_7) is then written into the location specified on the address pins (A_0 through A_{18}).

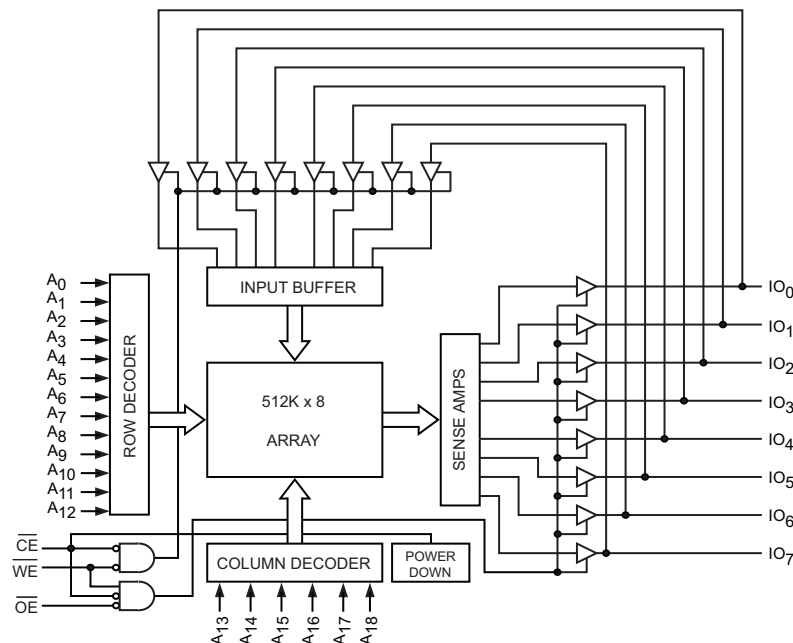
Reading from the device is accomplished by taking Chip Enable (\overline{CE}) and Output Enable (\overline{OE}) LOW while forcing Write Enable (\overline{WE}) HIGH. Under these conditions, the contents of the memory location specified by the address pins appear on the I/O pins.

The eight input and output pins (I/O_0 through I/O_7) are placed in a high impedance state when the device is deselected (\overline{CE} HIGH), the outputs are disabled (\overline{OE} HIGH), or during a write operation (\overline{CE} LOW, and \overline{WE} LOW).

The CY7C1049CV33 is available in standard 44-pin TSOP II package with center power and ground (revolutionary) pinout.

For best practice recommendations, refer to the Cypress application note [AN1064, SRAM System Guidelines](#).

Logic Block Diagram



Contents

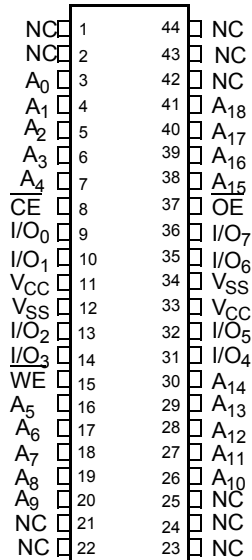
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Selection Guide

Description	-8	Unit
Maximum Access Time	8	ns
Maximum Operating Current	100	mA
Maximum CMOS Standby Current	10	mA

Pin Configuration

Figure 1. 44-pin TSOP II (Top View)



Pin Definitions

Pin Name	44-pin TSOP II Pin Number	I/O Type	Description
A ₀ –A ₁₈	3–7, 16–20, 26–30, 38–41	Input	Address inputs used to select one of the address locations.
I/O ₀ –I/O ₇	9, 10, 13, 14, 31, 32, 35, 36	Input/Output	Bidirectional data I/O lines. Used as input or output lines depending on operation.
NC ^[1]	1, 2, 21, 22, 23, 24, 25, 42, 43, 44	No Connect	No connects. This pin is not connected to the die.
WE	15	Input/Control	Write Enable input, active LOW. When selected LOW, a WRITE is conducted. When selected HIGH, a READ is conducted.
CE	8	Input/Control	Chip Enable input, active LOW. When LOW, selects the chip. When HIGH, deselects the chip.
OE	37	Input/Control	Output Enable, active LOW. Controls the direction of the I/O pins. When LOW, the I/O pins are allowed to behave as outputs. When deasserted HIGH, I/O pins are three-stated, and act as input data pins.
V _{SS} , GND	12, 34	Ground	Ground for the device. Should be connected to ground of the system.
V _{CC}	11, 33	Power Supply	Power supply inputs to the device.

Note

1. NC pins are not connected on the die.

Maximum Ratings

Exceeding maximum ratings may impair the useful life of the device. These user guidelines are not tested.

Storage Temperature -65 °C to +150 °C

Ambient Temperature with

Power Applied -55 °C to +125 °C

Supply Voltage on V_{CC} to Relative GND^[2] -0.5 V to +4.6 VDC

Voltage Applied to Outputs

in High Z State^[2] -0.5 V to $V_{CC} + 0.5$ V

Input Voltage^[2] -0.5 V to $V_{CC} + 0.5$ V

Current into Outputs (LOW) 20 mA

Operating Range

Range	Ambient Temperature	V_{CC}
Commercial	0 °C to +70 °C	3.3 V \pm 0.3 V

Electrical Characteristics

Over the Operating Range

Parameter	Description	Test Conditions	-8		Unit
			Min	Max	
V_{OH}	Output HIGH Voltage	$V_{CC} = \text{Min}; I_{OH} = -4.0$ mA	2.4	—	V
V_{OL}	Output LOW Voltage	$V_{CC} = \text{Min}; I_{OL} = 8.0$ mA	—	0.4	V
V_{IH}	Input HIGH Voltage		2.0	$V_{CC} + 0.3$	V
V_{IL}	Input LOW Voltage ^[2]		-0.3	0.8	V
I_{IX}	Input Load Current	$GND \leq V_I \leq V_C$	-1	+1	μ A
I_{CC}	V_{CC} Operating Supply Current	$V_{CC} = \text{Max}, f = f_{MAX} = 1/t_{RC}$	—	100	mA
I_{SB1}	Automatic CE Power Down Current —TTL Inputs	Max. $V_{CC}, CE \geq V_{IH}, V_{IN} \geq V_{IH}$ or $V_{IN} \leq V_{IL}, f = f_{MAX}$	—	40	mA
I_{SB2}	Automatic CE Power Down Current —CMOS Inputs	Max. $V_{CC}, CE \geq V_{CC} - 0.3$ V, $V_{IN} \geq V_{CC} - 0.3$ V, or $V_{IN} \leq 0.3$ V, $f = 0$	—	10	mA

Capacitance

Tested initially and after any design or process changes that may affect these parameters.

Parameter ^[3]	Description	Test Conditions	Max	Unit
C_{IN}	Input Capacitance	$T_A = 25$ °C, $f = 1$ MHz, $V_{CC} = 3.3$ V	8	pF
C_{OUT}	I/O Capacitance		8	pF

Thermal Resistance

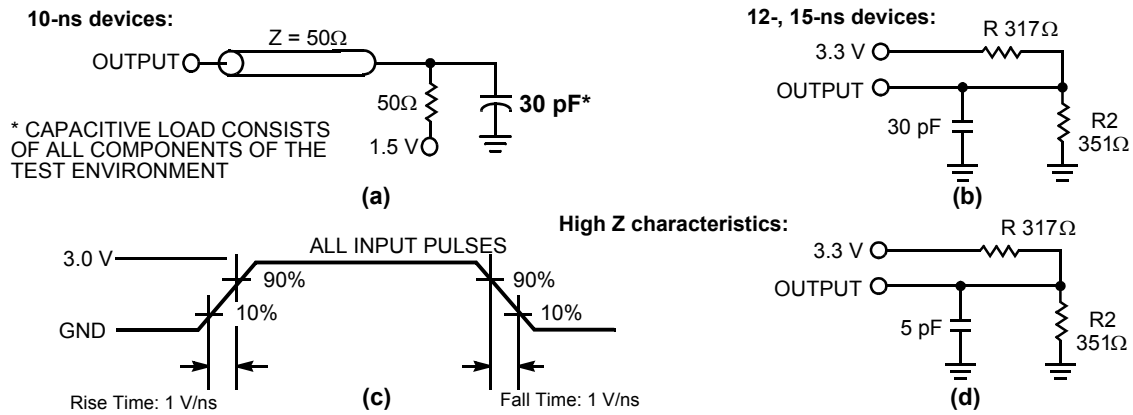
Tested initially and after any design or process changes that may affect these parameters.

Parameter ^[3]	Description	Test Conditions	44-pin TSOP-II	Unit
Θ_{JA}	Thermal Resistance (Junction to Ambient)	Test conditions follow standard test methods and procedures for measuring thermal impedance, per EIA / JESD51.	41.66	°C/W
Θ_{JC}	Thermal Resistance (Junction to Case)		10.56	°C/W

Notes

- $V_{IL}(\text{min}) = -2.0$ V and $V_{IH}(\text{max}) = V_{CC} + 0.5$ V for pulse durations of less than 20 ns.
- Tested initially and after any design or process changes that may affect these parameters.

Figure 2. AC Test Loads and Waveforms [4]



Note

4. AC characteristics (except High Z) for 10 ns parts are tested using the load conditions shown in [Figure 2 \(a\)](#). All other speeds are tested using the Thevenin load shown in [Figure 2 \(b\)](#). High Z characteristics are tested for all speeds using the test load shown in [Figure 2 \(d\)](#).

AC Switching Characteristics

Over the Operating Range ^[5]

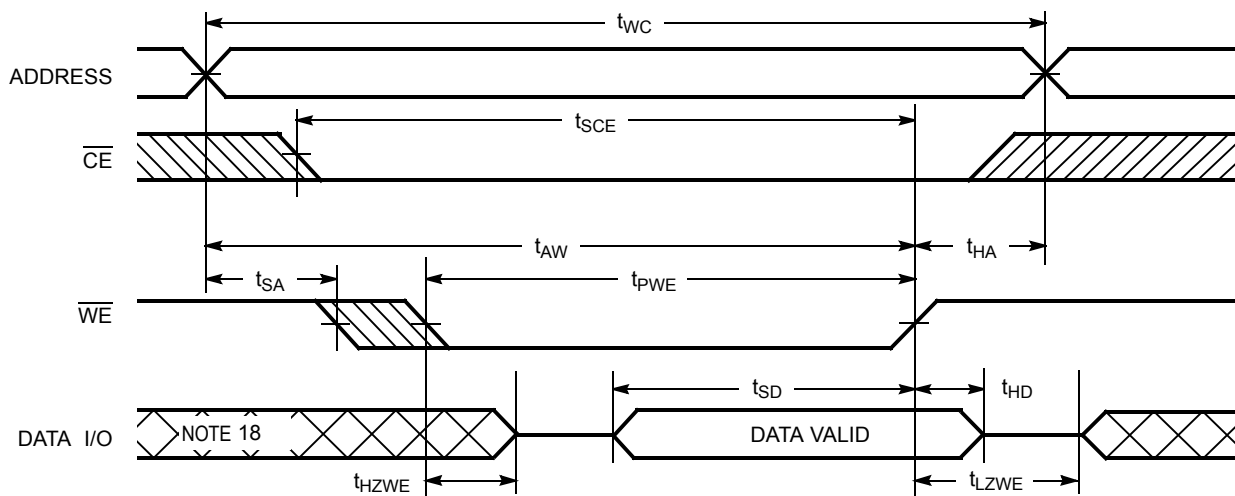
Parameter	Description	-8		Unit
		Min	Max	
Read Cycle				
t _{power} ^[6]	V _{CC} (typical) to the first access	100	—	μs
t _{RC}	Read Cycle Time	8	—	ns
t _{AA}	Address to Data Valid	—	8	ns
t _{OHA}	Data Hold from Address Change	3	—	ns
t _{ACE}	$\overline{\text{CE}}$ LOW to Data Valid	—	8	ns
t _{DOE}	$\overline{\text{OE}}$ LOW to Data Valid	—	5	ns
t _{LZOE}	$\overline{\text{OE}}$ LOW to Low Z	0	—	ns
t _{HZOE}	$\overline{\text{OE}}$ HIGH to High Z ^[7, 8]	—	4	ns
t _{LZCE}	$\overline{\text{CE}}$ LOW to Low Z ^[8]	3	—	ns
t _{HZCE}	$\overline{\text{CE}}$ HIGH to High Z ^[7, 8]	—	4	ns
t _{PU}	$\overline{\text{CE}}$ LOW to Power Up	0	—	ns
t _{PD}	$\overline{\text{CE}}$ HIGH to Power Down	—	8	ns
Write Cycle ^[9, 10]				
t _{WC}	Write Cycle Time	8	—	ns
t _{SCE}	$\overline{\text{CE}}$ LOW to Write End	6	—	ns
t _{AW}	Address Setup to Write End	6	—	ns
t _{HA}	Address Hold from Write End	0	—	ns
t _{SA}	Address Setup to Write Start	0	—	ns
t _{PWE}	$\overline{\text{WE}}$ Pulse Width	6	—	ns
t _{SD}	Data Setup to Write End	4	—	ns
t _{HD}	Data Hold from Write End	0	—	ns
t _{LZWE}	$\overline{\text{WE}}$ HIGH to Low Z ^[8]	3	—	ns
t _{HZWE}	$\overline{\text{WE}}$ LOW to High Z ^[7, 8]	—	4	ns

Notes

- Test conditions assume signal transition time of 3 ns or less, timing reference levels of 1.5 V, input pulse levels of 0 to 3.0 V.
- t_{POWER} gives the minimum amount of time that the power supply should be at stable, typical V_{CC} values until the first memory access can be performed.
- t_{HZOE} , t_{HZCE} , and t_{HZWE} are specified with a load capacitance of 5 pF as in part (d) of AC Test Loads. Transition is measured ± 500 mV from steady-state voltage.
- At any temperature and voltage condition, t_{HZCE} is less than t_{LZCE} , t_{HZOE} is less than t_{LZOE} , and t_{HZWE} is less than t_{LZWE} for any device.
- The internal Write time of the memory is defined by the overlap of $\overline{\text{CE}}$ LOW, and $\overline{\text{WE}}$ LOW. $\overline{\text{CE}}$ and $\overline{\text{WE}}$ must be LOW to initiate a Write, and the transition of either of these signals can terminate the Write. The input data setup and hold timing should be referenced to the leading edge of the signal that terminates the Write.
- The minimum Write cycle time for Write Cycle No. 3 ($\overline{\text{WE}}$ controlled, $\overline{\text{OE}}$ LOW) is the sum of t_{HZWE} and t_{SD} .

Switching Waveforms (continued)

Figure 6. Write Cycle No. 2 ($\overline{\text{WE}}$ Controlled, $\overline{\text{OE}}$ LOW) ^[17]



Truth Table

$\overline{\text{CE}}$	$\overline{\text{OE}}$	$\overline{\text{WE}}$	I/O ₀ –I/O ₇	Mode	Power
H	X	X	High Z	Power Down	Standby (I_{SB})
L	L	H	Data Out	Read	Active (I_{CC})
L	X	L	Data In	Write	Active (I_{CC})
L	H	H	High Z	Selected, Outputs Disabled	Active (I_{CC})

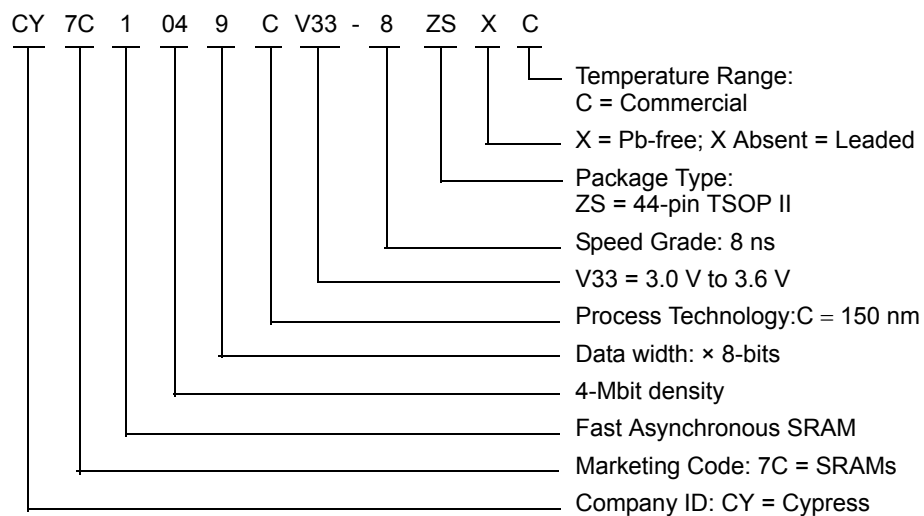
Notes

17. If $\overline{\text{CE}}$ goes HIGH simultaneously with $\overline{\text{WE}}$ HIGH, the output remains in high impedance state.
 18. During this period, the I/Os are in output state. Do not apply input signals.

Ordering Information

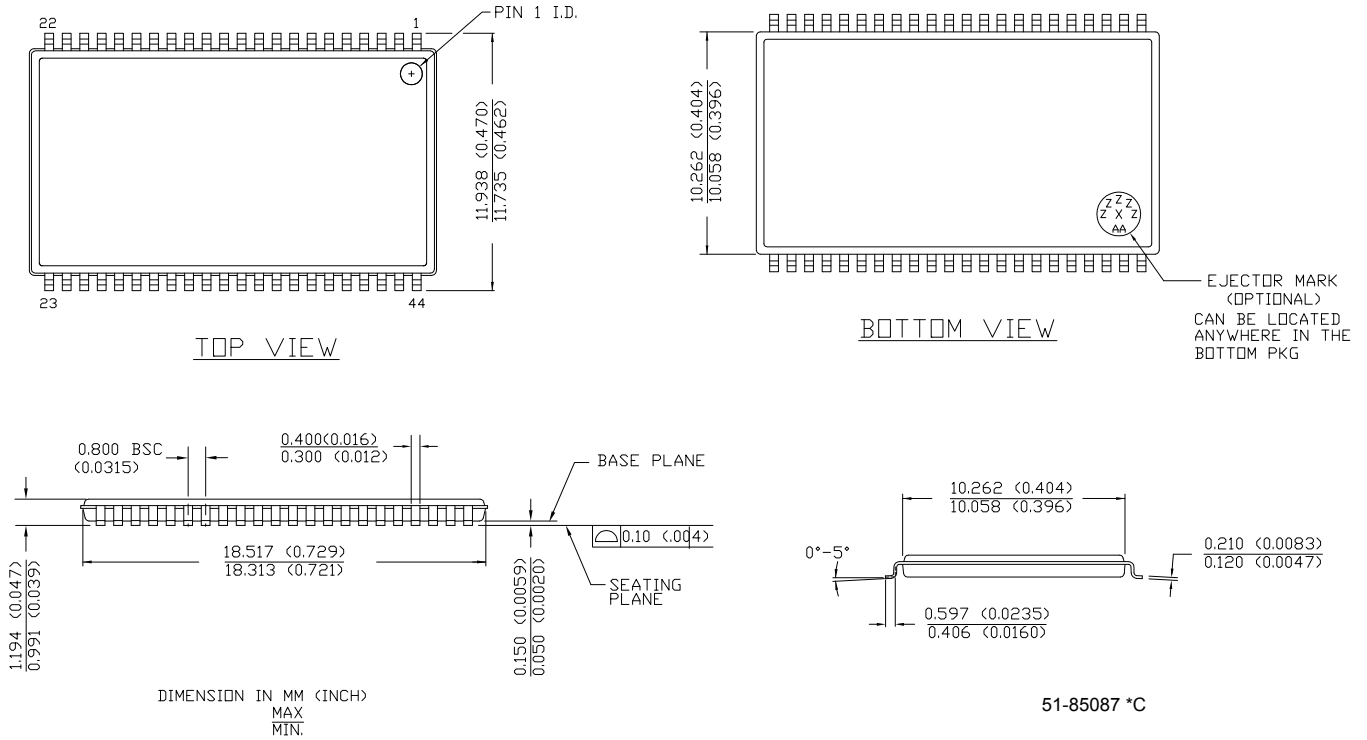
Speed (ns)	Ordering Code	Package Diagram	Package Type	Operating Range
8	CY7C1049CV33-8ZSXC	51-85087	44-pin TSOP II (Pb-free)	Commercial

Ordering Code Definitions



Package Diagram

Figure 7. 44-pin TSOP II, 51-85087



Acronyms

Acronym	Description
CMOS	complementary metal oxide semiconductor
CE	Chip Enable
OE	Output Enable
RAM	Random Access Memory
I/O	Input/Output
SOJ	small outline J-lead
TTL	transistor-transistor logic
TSOP	thin small outline package
WE	Write Enable

Document Conventions

Units of Measure

Symbol	Unit of Measure
Ω	ohms
ns	nano seconds
V	Volts
μ s	micro seconds
μ A	micro Amperes
mA	milli Amperes
mm	milli meter
ms	milli seconds
MHz	Mega Hertz
pF	pico Farad
%	percent
mW	milli Watts
W	Watts
$^{\circ}$ C	degree Celcius

Document History Page

Document Title: CY7C1049CV33 4-Mbit (512 K × 8) Static RAM Document Number: 38-05006				
Rev.	ECN	Orig. of Change	Submission Date	Description of Change
**	112569	HGK	03/06/02	New data sheet
*A	114091	DFP	04/25/02	Changed Tpower unit from ns to μs
*B	116479	CEA	09/16/02	Add applications foot note to data sheet, page 1.
*C	262949	RKF	See ECN	Added Automotive-E Specs Added Θ_{JA} and Θ_{JC} values on Page #3.
*D	300091	RKF	See ECN	Added -20-ns Speed bin
*E	344595	SYT	See ECN	Added Pb-free package on page #8 Removed shading for CY7C1049CV33-15ZSXE in the ordering Information on page 9
*F	2615344	VKN/PYRS	12/03/08	Added Automotive-A information Removed 8 ns and 20 ns speed bins, Changed t _{POWER} spec from 1 μs to 100 μs, Updated Ordering Information table.
*G	2841563	NXR/	01/07/2010	Added CY7C1049CV33-10VXA to Ordering Info table.
*H	2898958	AJU	03/25/10	Removed inactive parts from the ordering informaiton table. Updated package diagrams.
*I	2954734	AJU	06/30/2010	New Part Number added CY7C1049CV33-10ZXC to Ordering Info table.
*J	3072834	PRAS	11/12/2010	Removed obsolete parts and updated package diagram.
*K	3185812	PRAS	03/02/2011	Updated Features . Updated Functional Description . Updated Selection Guide (Added -8 ns speed grade devices and removed -10 ns, -12 ns, and -15 ns speed grade devices). Removed Figure 36-pin SOJ (Top View) in Pin Configuration . Updated Electrical Characteristics (Added -8 ns speed grade devices and removed -10 ns, -12 ns, and -15 ns speed grade devices). Deleted 36-pin SOJ column in Thermal Resistance . Updated AC Switching Characteristics (Added -8 ns speed grade devices and removed -10 ns, -12 ns, and -15 ns speed grade devices). Added Units of Measure . Dislodged Automotive information to 001-67511. Removed SOJ package related information in all instances in the document.

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